

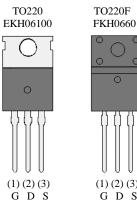
### **Features**

- V<sub>DS</sub>-----60 V
- I<sub>D</sub> ------ 100 A (EKH06100, SKH06100)
- $R_{DS(ON)}$  ------ 3.8 m $\Omega$  typ. ( $V_{GS} = 10$  V,  $I_D = 50$  A)
- Built-in Gate protect diode
- 100% UIL tested
- RoHS Compliant

## **Applications**

- Low Voltage DC Motor driver
- Solenoid driver

# Package



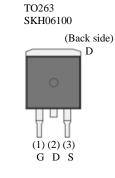
**Equivalent circuit** 

G(1) O-

(1) (2) (3) G D S

D(2)

S(3)



D

Not to scale

P	Product Lineup						
	Products	I <sub>D</sub>	P <sub>D</sub>	$\theta_{j\text{-}C}$	R <sub>DS(ON)</sub> (typ.)	Package	
		(A)	(W)	(°C/W)	$(m\Omega)$	0	
	EKH06100	100	100	1.25	3.8	TO220	
	FKH0660	60	40	3.13	3.8	TO220F	
	SKH06100	100	100	1.25	3.6	TO263	

# **Absolute Maximum Ratings**

• Unless otherwise specified,  $T_A = 25 \ ^{\circ}C$ 

			Rating			
Characteristic	Symbol	Test conditions	EKH06100 SKH06100	FKH0660	Unit	
Drain to Source Voltage	V <sub>DSS</sub>		60		V	
Gate to Source Voltage	V <sub>GSS</sub>		± 2	20	V	
Continuous Drain Current	I <sub>D(DC)</sub>	$T_C = 25$ °C, Package Limited	100 <sup>(1)</sup> 60		А	
Pulsed Drain Current	I <sub>D(PULSE)</sub>	$\begin{array}{l} PW \leq 100 \ \mu s \\ Duty \ cycle \leq 1 \ \% \end{array}$	200		А	
Continuous Diode Forward Current	I <sub>SD(DC)</sub>	$T_C = 25$ °C, Package Limited	100 (1)	60	А	
Diode Pulse Current	I <sub>SD(PULSE)</sub>	$\begin{array}{l} PW \leq 100 \ \mu s \\ Duty \ cycle \leq 1 \ \% \end{array}$	200		А	
Single Pulse Avalanche Energy	E <sub>AS</sub>	$V_{DD} = 20 \text{ V}, I_{LP} = I_{D(DC)}$ unclamped, $R_g = 50 \Omega$ See Figure 1	300 (2)		mJ	
Maximum avalanche current	I <sub>AS</sub>		100	60	А	
Maximum Power Dissipation	P <sub>D</sub>	$T_C = 25 \ ^{\circ}C$	100	40	W	
Thermal Resistance	$\theta_{j\text{-}C}$		1.25	3.13	°C/W	
Thermal Resistance	$\theta_{j\text{-}A}$		62.5		°C/W	
Operating Junction Temperature	Tj		15	50	°C	
Storage Temperature	T <sub>stg</sub>		– 55 t	o 150	°C	

<sup>(1)</sup>  $PW \le 100 \ \mu s$ 

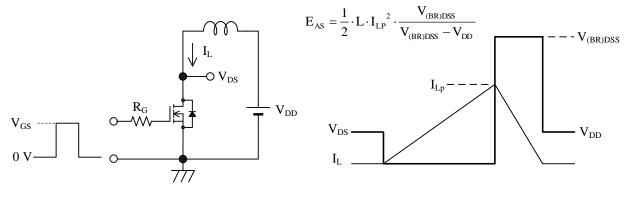
<sup>(2)</sup> EKH06100 / SKH06100 :  $L = 40 \mu H$ , FKH0660 :  $L = 100 \mu H$ 

## **Electrical Characteristics**

• Unless otherwise specified,  $T_A = 25 \ ^{\circ}C$ 

$\frac{1}{Characteristic}$	Symbol	Test Co	onditions	Min.	Тур.	Max.	Unit
Drain to Source Breakdown Voltage	V <sub>(BR)DSS</sub>	$I_D = 100 \ \mu A, \ V_{GS} = 0 \ V$		60	-	_	V
Drain to Source Breakdown Voltage Temp. Coefficient	$\Delta V_{(BR)DSS}$	$I_D = 1 \text{ mA}, V_{GS} = 0 \text{ V}$		Ι	50	_	mV/°C
Drain to Source Leakage Current	I <sub>DSS</sub>	$V_{\rm DS} = 60 \ {\rm V}, {\rm V}$	$V_{\rm GS} = 0 \rm V$	-	-	100	μA
Gate to Source Leakage Current	I <sub>GSS</sub>	$V_{GS} = \pm 15 V$		-	-	$\pm 20$	μA
Gate Threshold Voltage	V <sub>TH</sub>	$V_{\rm DS} = 10 \ {\rm V}, {\rm I}$	$I_{\rm D} = 1  \mathrm{mA}$	2.0	-	4.0	V
Gate Threshold Voltage Temp. Coefficient	$\Delta V_{TH}$	$V_{\rm DS} = 10 \ \rm V, \ \rm I$	$I_{\rm D} = 1  \mathrm{mA}$	_	- 9	_	mV/°C
Static Drain to Source	R <sub>DS(ON)</sub>	$I_D = 50 \text{ A}$ $V_{GS} = 10 \text{ V}$	EKH06100 FKH0660	1	3.8	5.0	mΩ
On-Resistance	TOS(ON)		SKH06100		3.6	4.8	mΩ
Forward Transfer Admittance	y <sub>fs</sub>	$V_{\rm DS} = 10 \ \rm V, \ \rm I$	$I_{\rm D} = 50  {\rm A}$	-	140	_	S
Input Capacitance	C <sub>iss</sub>	$V_{DS} = 10 V$ $V_{GS} = 0 V$ $F = 1 MHz$		-	11500	—	pF
Output Capacitance	C <sub>oss</sub>			-	1100		
Reverse Transfer Capacitance	C <sub>rss</sub>			-	820	—	
Total Gate Charge	Qg	$V_{DD} \doteq 30 V$		-	165	_	
ate to Source Charge Q <sub>gs</sub>		$I_{\rm D} = 50 \text{ A}$ $R_{\rm L} = 0.6 \Omega$		-	55	_	nC
Gate to Drain Charge	Q <sub>gd</sub>	$V_{GS} = 10 \text{ V}$		-	35	_	]
Turn-On Delay Time	t <sub>d(on)</sub>	$V_{DD} \rightleftharpoons 30 \text{ V}$ $I_D = 50 \text{ A}$ $R_L = 0.6 \Omega$ $V_{GS} = 10 \text{ V}$ $R_g = 10 \Omega$ See Figure 2		-	60	_	ns
Rise Time	t <sub>r</sub>			-	140	—	
Turn-Off Delay Time	t <sub>d(off)</sub>			-	210	_	
Fall Time	t <sub>f</sub>			-	110	-	
Source-Drain Diode Forward Voltage	V <sub>SD</sub>	$I_{SD} = 100 \text{ A},$	$V_{GS} = 0 V$		1.0	1.5	V
Source-Drain Diode Reverse Recovery Time	t <sub>rr</sub>	$I_{SD} = 100 \text{ A}$ di/dt = 100 A/ $\mu$ s See Figure 3		_	70	_	ns
Source-Drain Diode Recovery Charge	Q <sub>rr</sub>			_	160	_	ns

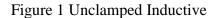
## **Test Circuit and Waveform**

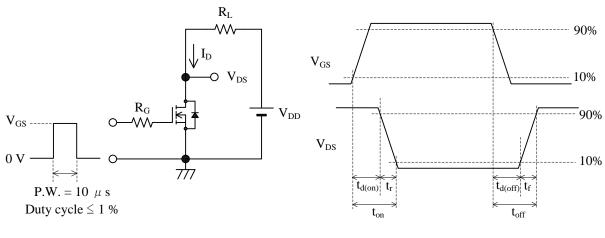


(a) Test Circuit

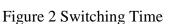
(b) Waveforms

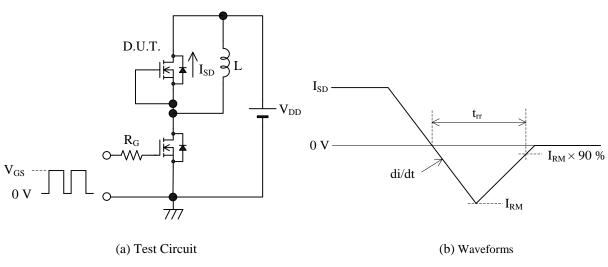
(b) Waveforms

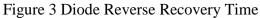






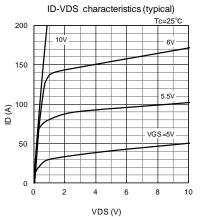


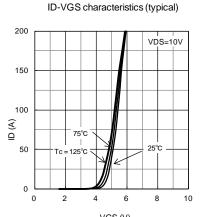


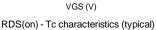


# EKH06100 / FKH0660 / SKH06100

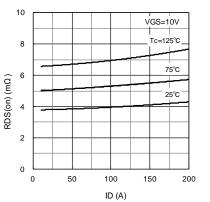
#### **Performance Curves**





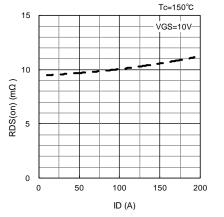


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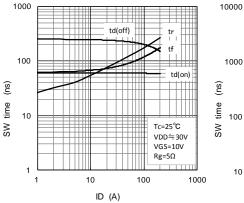


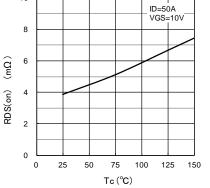
RDS(on)-ID characteristics (typical)

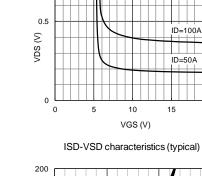
RDS(on)-ID characteristics (maximum)



SW time - ID characteristics (typical)





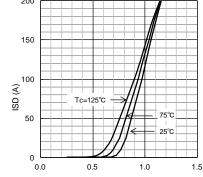


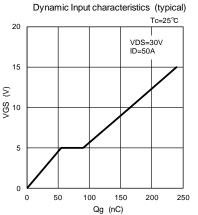
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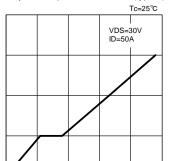
VDS-VGS characteristics (typical)

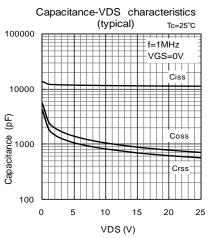
Tc=25°C

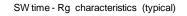
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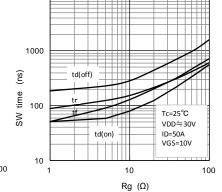


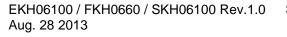








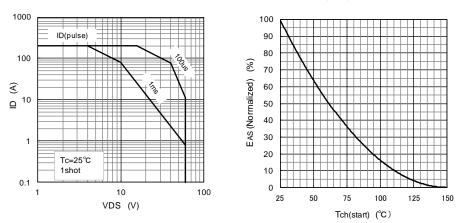




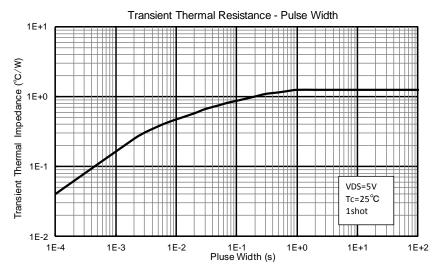
# EKH06100 / FKH0660 / SKH06100



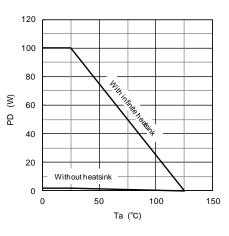
EAS - Tc(start) Characteristics



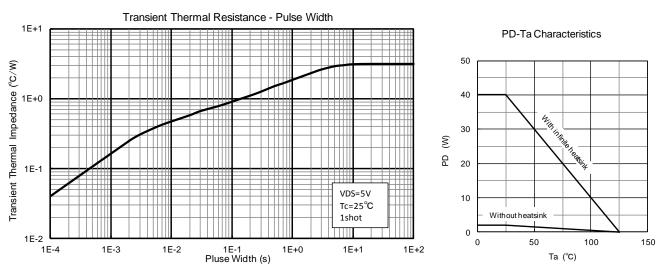
EKH06100 / SKH06100





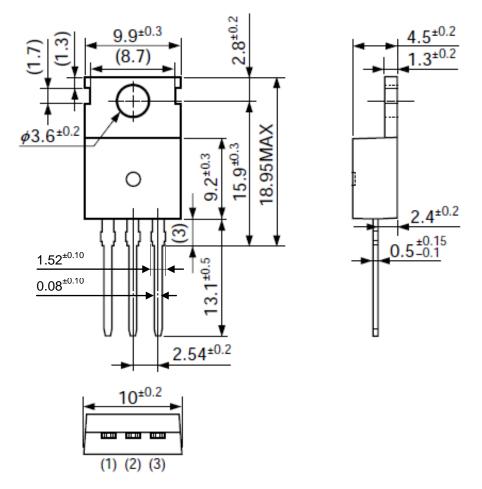


FKH0660



# Package Outline

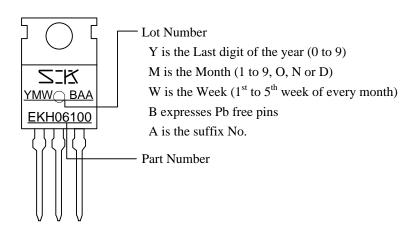
**TO220** 



## NOTES:

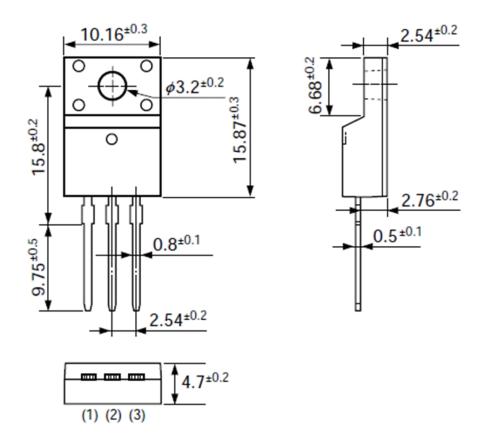
- 1) Dimension is in millimeters.
- 2) Pin treatment Pb-free. Device composition compliant with the RoHS directive

# **Marking Diagram**



# **Package Outline**

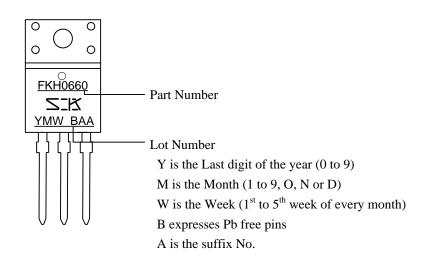
TO220F



### NOTES:

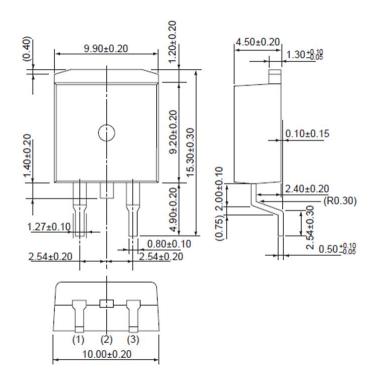
- 1) Dimension is in millimeters.
- 2) Pin treatment Pb-free. Device composition compliant with the RoHS directive

## **Marking Diagram**



# **Package Outline**

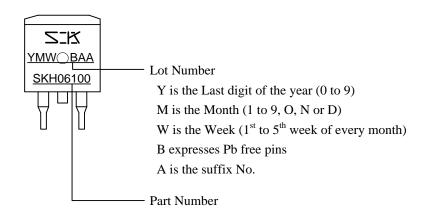
TO263



## NOTES:

- 1) Dimension is in millimeters.
- 2) Pin treatment Pb-free. Device composition compliant with the RoHS directive

## **Marking Diagram**



## **OPERATING PRECAUTIONS**

In the case that you use Sanken products or design your products by using Sanken products, the reliability largely depends on the degree of derating to be made to the rated values. Derating may be interpreted as a case that an operation range is set by derating the load from each rated value or surge voltage or noise is considered for derating in order to assure or improve the reliability. In general, derating factors include electric stresses such as electric voltage, electric current, electric power etc., environmental stresses such as ambient temperature, humidity etc. and thermal stress caused due to self-heating of semiconductor products. For these stresses, instantaneous values, maximum values and minimum values must be taken into consideration. In addition, it should be noted that since power devices or IC's including power devices have large self-heating value, the degree of derating of junction temperature affects the reliability significantly.

Because reliability can be affected adversely by improper storage environments and handling methods, please observe the following cautions.

#### **Cautions for Storage**

- Ensure that storage conditions comply with the standard temperature (5 to 35°C) and the standard relative humidity (around 40 to 75%); avoid storage locations that experience extreme changes in temperature or humidity.
- Avoid locations where dust or harmful gases are present and avoid direct sunlight.
- Reinspect for rust on leads and solderability of the products that have been stored for a long time.

#### **Cautions for Testing and Handling**

When tests are carried out during inspection testing and other standard test periods, protect the products from power surges from the testing device, shorts between the product pins, and wrong connections. Ensure all test parameters are within the ratings specified by Sanken for the products.

#### **Remarks About Using Silicone Grease with a Heatsink**

- When silicone grease is used in mounting the products on a heatsink, it shall be applied evenly and thinly. If more silicone grease than required is applied, it may produce excess stress.
- Volatile-type silicone greases may crack after long periods of time, resulting in reduced heat radiation effect. Silicone greases with low consistency (hard grease) may cause cracks in the mold resin when screwing the products to a heatsink.

Our recommended silicone greases for heat radiation purposes, which will not cause any adverse effect on the product life, are indicated below:

Туре	Suppliers			
G746	Shin-Etsu Chemical Co., Ltd.			
YG6260	Momentive Performance Materials Inc.			
SC102	Dow Corning Toray Co., Ltd.			

#### **Cautions for Mounting to a Heatsink**

- When the flatness around the screw hole is insufficient, such as when mounting the products to a heatsink that has an extruded (burred) screw hole, the products can be damaged, even with a lower than recommended screw torque. For mounting the products, the mounting surface flatness should be 0.05mm or less.
- Please select suitable screws for the product shape. Do not use a flat-head machine screw because of the stress to the products. Self-tapping screws are not recommended. When using self-tapping screws, the screw may enter the hole diagonally, not vertically, depending on the conditions of hole before threading or the work situation. That may stress the products and may cause failures.
- Recommended screw torque:

Package	Recommended Screw Torque		
TO-220, TO-220F	0.490 to 0.686 N·m (5 to 7 kgf·cm)		
TO-3P, TO-3PF	0.686 to 0.882 N·m (7 to 9 kgf·cm)		
SLA	0.588 to 0.784 N•m (6 to 8 kgf•cm)		

• For tightening screws, if a tightening tool (such as a driver) hits the products, the package may crack, and internal stress fractures may occur, which shorten the lifetime of the electrical elements and can cause catastrophic failure. Tightening with an air driver makes a substantial impact. In addition, a screw torque higher than the set torque can be applied and the package may be damaged. Therefore, an electric driver is recommended.

When the package is tightened at two or more places, first pre-tighten with a lower torque at all places, then tighten with the specified torque. When using a power driver, torque control is mandatory.

• Please pay special attention about the slack of the press mold. In case that the hole diameter of the heatsink is less than 4 mm, it may cause the resin crack at tightening.

#### Soldering

• When soldering the products, please be sure to minimize the working time, within the following limits:

### TO220 and TO220F

- $260 \pm 5 \,^{\circ}\text{C}$  10  $\pm 1 \,\text{s}$  (Flow, 2 times)
- $380 \pm 10$  °C  $3.5 \pm 0.5$  s (Soldering iron, 1 time)

Soldering should be at a distance of at least 1.5 mm from the body of the products.

TO263

- Reflow Preheat ;  $180 \degree C / 90 \pm 30 \text{ s}$ 
  - Solder heating ;  $250 \text{ °C} / 10 \pm 1s$  (260 °C peak, 2 times)

• Soldering iron;  $380 \pm 10 \text{ °C} / 3.5 \pm 0.5 \text{ (1 time)}$ 

### **Electrostatic Discharge**

- When handling the products, the operator must be grounded. Grounded wrist straps worn should have at least 1MΩ of resistance from the operator to ground to prevent shock hazard, and it should be placed near the operator.
- Workbenches where the products are handled should be grounded and be provided with conductive table and floor mats.
- When using measuring equipment such as a curve tracer, the equipment should be grounded.
- When soldering the products, the head of soldering irons or the solder bath must be grounded in order to prevent leak voltages generated by them from being applied to the products.
- The products should always be stored and transported in Sanken shipping containers or conductive containers, or be wrapped in aluminum foil.

## **IMPORTANT NOTES**

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- Sanken products listed in this document are designed and intended for the use as components in general purpose electronic equipment or apparatus (home appliances, office equipment, telecommunication equipment, measuring equipment, etc.).

When considering the use of Sanken products in the applications where higher reliability is required (transportation equipment and its control systems, traffic signal control systems or equipment, fire/crime alarm systems, various safety devices, etc.), and whenever long life expectancy is required even in general purpose electronic equipment or apparatus, please contact your nearest Sanken sales representative to discuss, prior to the use of the products herein.

The use of Sanken products without the written consent of Sanken in the applications where extremely high reliability is required (aerospace equipment, nuclear power control systems, life support systems, etc.) is strictly prohibited.

- When using the products specified herein by either (i) combining other products or materials therewith or (ii) physically, chemically or otherwise processing or treating the products, please duly consider all possible risks that may result from all such uses in advance and proceed therewith at your own responsibility.
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- Sanken assumes no responsibility for any troubles, such as dropping products caused during transportation out of Sanken's distribution network.
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